### Features

- Fast Read Access Time 150 ns
- Automatic Page Write Operation
  - Internal Address and Data Latches for 64 Bytes
  - Internal Control Timer
- Fast Write Cycle Times
  - Page Write Cycle Time: 3 ms or 10 ms Maximum
  - 1 to 64-byte Page Write Operation
- Low Power Dissipation
  - 50 mA Active Current
  - 200 µA CMOS Standby Current
- Hardware and Software Data Protection
- DATA Polling for End of Write Detection
- High Reliability CMOS Technology
  - Endurance: 10<sup>4</sup> or 10<sup>5</sup> Cycles
  - Data Retention: 10 Years
- Single 5V  $\pm$  10% Supply
- CMOS and TTL Compatible Inputs and Outputs
- JEDEC Approved Byte-wide Pinout
- Full Military and Industrial Temperature Ranges
- Green (Pb/Halide-free) Packaging Option

### 1. Description

The AT28C256 is a high-performance electrically erasable and programmable readonly memory. Its 256K of memory is organized as 32,768 words by 8 bits. Manufactured with Atmel's advanced nonvolatile CMOS technology, the device offers access times to 150 ns with power dissipation of just 440 mW. When the device is deselected, the CMOS standby current is less than 200  $\mu$ A.

The AT28C256 is accessed like a Static RAM for the read or write cycle without the need for external components. The device contains a 64-byte page register to allow writing of up to 64 bytes simultaneously. During a write cycle, the addresses and 1 to 64 bytes of data are internally latched, freeing the address and data bus for other operations. Following the initiation of a write cycle, the device will automatically write the latched data using an internal control timer. The end of a write cycle can be detected by DATA Polling of I/O7. Once the end of a write cycle has been detected a new access for a read or write can begin.

Atmel's AT28C256 has additional features to ensure high quality and manufacturability. The device utilizes internal error correction for extended endurance and improved data retention characteristics. An optional software data protection mechanism is available to guard against inadvertent writes. The device also includes an extra 64 bytes of EEPROM for device identification or tracking.

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# 256K (32K x 8) Paged Parallel EEPROM

# AT28C256

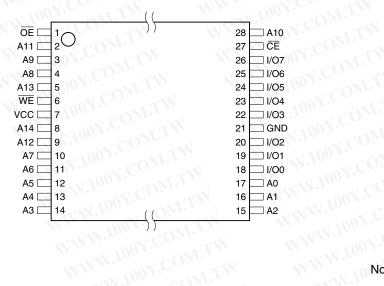
0006J-PEEPR-10/06



# Pin Configurations 2.

Pin Name	Function
A0 - A14	Addresses
CE	Chip Enable
OE	Output Enable
WE CONTRACTOR	Write Enable
I/O0 - I/O7	Data Inputs/Outputs
NC	No Connect
DC CONTRACT	Don't Connect

#### 28-lead TSOP Top View 2.1



#### 32-pad LCC, 28-lead PLCC Top View 2.3

A6 🗆 5 O 29 🗆 A8	
A5 🗌 6 28 🗋 A9	
A4 🗌 7 27 🗋 A1	1
A3 🗌 8 26 🗋 NC	;
A2 🗆 9 25 🗖 OE	5
A1 🗌 10 24 🗋 A1	0
A0 🗌 11 23 🗋 CE	1
NC 12 22 1/0	7
	6
20 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	
1/01 DC 1/03 1/05	
≥ ≥ ₽ □ ≥ ≥ ≥	

WWW.100Y.COM.TW Note: PLCC package pins 1 and 17 are Don't Connect.

## 100Y.COM.TW MOY.COM.TW 2.2 28-lead PGA Top View

4	3	1	27	26
A6	A7	A14	WE	A13
5	2	28	24	25
A5	A12	VCC	A9	A8
7	6		22	23
A3	A4		0E	A11
9	8	W	20	21
A1	A2		CE	A10
11	10	14	16	19
I/O0	A0	GND	I/O4	I/O7
12	13	15	17	18
I/O1	I/O2	I/O3	I/O5	I/O6
			1.1	

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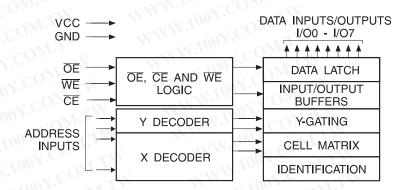


### 2.4 28-lead Cerdip/PDIP/Flatpack/SOIC – WWW.100 **Top View** WWW.100Y.COM.

	NW.10° CON.
1	28 🗀 VCC
2	27 🗔 WE
3	26 🗖 A13
4	25 🗖 A8
5	24 🗖 A9
6	23 🗖 A11
7	22 🗖 ŌĒ
8	21 🗖 A10
9	20 🗖 CE
10	19 🔲 1/07
11	18 🗔 I/O6
12	17 🗖 1/05
13	16 🗔 I/O4
14	15 🗖 I/O3
	N N Y
	3 4 5 6 7 8 9 10 11 12 13

WW.100X.COM.TW

## 3. Block Diagram



### 4. Device Operation

### 4.1 Read

The AT28C256 is accessed like a Static RAM. When  $\overline{CE}$  and  $\overline{OE}$  are low and  $\overline{WE}$  is high, the data stored at the memory location determined by the address pins is asserted on the outputs. The outputs are put in the high impedance state when either  $\overline{CE}$  or  $\overline{OE}$  is high. This dual-line control gives designers flexibility in preventing bus contention in their system.

### 4.2 Byte Write

A low pulse on the  $\overline{WE}$  or  $\overline{CE}$  input with  $\overline{CE}$  or  $\overline{WE}$  low (respectively) and  $\overline{OE}$  high initiates a write cycle. The address is latched on the falling edge of  $\overline{CE}$  or  $\overline{WE}$ , whichever occurs last. The data is latched by the first rising edge of  $\overline{CE}$  or  $\overline{WE}$ . Once a byte write has been started it will automatically time itself to completion. Once a programming operation has been initiated and for the duration of t<sub>WC</sub>, a read operation will effectively be a polling operation.

### 4.3 Page Write

The page write operation of the AT28C256 allows 1 to 64 bytes of data to be written into the device during a single internal programming period. A page write operation is initiated in the same manner as a byte write; the first byte written can then be followed by 1 to 63 additional bytes. Each successive byte must be written within 150  $\mu$ s (t<sub>BLC</sub>) of the previous byte. If the t<sub>BLC</sub> limit is exceeded the AT28C256 will cease accepting data and commence the internal programming operation. All bytes during a page write operation must reside on the same page as defined by the state of the A6 - A14 inputs. For each WE high to low transition during the page write operation, A6 - A14 must be the same.

The A0 to A5 inputs are used to specify which bytes within the page are to be written. The bytes may be loaded in any order and may be altered within the same load period. Only bytes which are specified for writing will be written; unnecessary cycling of other bytes within the page does not occur.

### 4.4 DATA Polling

The AT28C256 features DATA Polling to indicate the end of a write cycle. During a byte or page write cycle an attempted read of the last byte written will result in the complement of the written data to be presented on I/O7. Once the write cycle has been completed, true data is valid on all outputs, and the next write cycle may begin. DATA Polling may begin at anytime during the write cycle.

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#### 4.5 Toggle Bit

In addition to DATA Polling the AT28C256 provides another method for determining the end of a write cycle. During the write operation, successive attempts to read data from the device will result in I/O6 toggling between one and zero. Once the write has completed, I/O6 will stop tog-gling and valid data will be read. Reading the toggle bit may begin at any time during the write cycle.

#### 4.6 Data Protection

If precautions are not taken, inadvertent writes may occur during transitions of the host system power supply. Atmel has incorporated both hardware and software features that will protect the memory against inadvertent writes.

#### 4.6.1 Hardware Protection

Hardware features protect against inadvertent writes to the AT28C256 in the following ways: (a)  $V_{CC}$  sense – if  $V_{CC}$  is below 3.8V (typical) the write function is inhibited; (b)  $V_{CC}$  power-on delay – once  $V_{CC}$  has reached 3.8V the device will automatically time out 5 ms (typical) before allowing a write; (c) write inhibit – holding any one of  $\overline{OE}$  low,  $\overline{CE}$  high or  $\overline{WE}$  high inhibits write cycles; and (d) noise filter – pulses of less than 15 ns (typical) on the  $\overline{WE}$  or  $\overline{CE}$  inputs will not initiate a write cycle.

#### 4.6.2 Software Data Protection

A software controlled data protection feature has been implemented on the AT28C256. When enabled, the software data protection (SDP), will prevent inadvertent writes. The SDP feature may be enabled or disabled by the user; the AT28C256 is shipped from Atmel with SDP disabled.

SDP is enabled by the host system issuing a series of three write commands; three specific bytes of data are written to three specific addresses (refer to "Software Data Protection" algorithm). After writing the 3-byte command sequence and after  $t_{WC}$  the entire AT28C256 will be protected against inadvertent write operations. It should be noted, that once protected the host may still perform a byte or page write to the AT28C256. This is done by preceding the data to be written by the same 3-byte command sequence used to enable SDP.

Once set, SDP will remain active unless the disable command sequence is issued. Power transitions do not disable SDP and SDP will protect the AT28C256 during power-up and power-down conditions. All command sequences must conform to the page write timing specifications. The data in the enable and disable command sequences is not written to the device and the memory addresses used in the sequence may be written with data in either a byte or page write operation.

After setting SDP, any attempt to write to the device without the 3-byte command sequence will start the internal write timers. No data will be written to the device; however, for the duration of  $t_{WC}$ , read operations will effectively be polling operations.

#### 4.7 Device Identification

An extra 64 bytes of EEPROM memory are available to the user for device identification. By raising A9 to 12V  $\pm$ 0.5V and using address locations 7FC0H to 7FFFH the additional bytes may be written to or read from in the same manner as the regular memory array.

### 4.8 Optional Chip Erase Mode

The entire device can be erased using a 6-byte software code. Please see "Software Chip Erase" application note for details.

4 **AT28C256** 

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#### 5. **DC and AC Operating Range**

		AT28C256-15	AT28C256-20	AT28C256-25	AT28C256-35
Operating Temperature	Ind.	-40°C - 85°C	WW.IV	ONL.	
(Case)	Mil.	-55°C - 125°C	-55°C - 125°C	-55°C - 125°C	-55°C - 125°C
V <sub>CC</sub> Power Supply	WW 100	5V ±10%	5V ±10%	5V ±10%	5V ±10%

### Operating Modes 6.

Mode	CE	OE	WE	I/O
Read	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	D <sub>OUT</sub>
Write <sup>(2)</sup>	VIL	V <sub>IH</sub>	C V <sub>IL</sub>	D <sub>IN</sub>
Standby/Write Inhibit	V <sub>IH</sub>	X <sup>(1)</sup>	X	High Z
Write Inhibit	X.100 X.OMA	x	VIII	
Write Inhibit	X	V <sub>IL</sub>	X-0M-1	≪1
Output Disable	X	V <sub>IH</sub>	X 100 X	High Z
Chip Erase	VIL	V <sub>H</sub> <sup>(3)</sup>	VIL	High Z

#### **Absolute Maximum Ratings\*** 7.

	9 N N N N N N N N N N N N N N N N N N N		
Temperature under Bias	55°C to +125°C	*NOTICE:	Stresses Maximur
Storage Temperature	65°C to +150°C		age to th
All Input Voltages	WWW.Do		functiona other cor
(including NC Pins) with Respect to Ground	0.6V to +6.25V		operation implied.
All Output Voltages with Respect to Ground	0.6V to V <sub>CC</sub> + 0.6V		conditior device re
Voltage on $\overline{OE}$ and A9 with Respect to Ground	0.6V to +13.5V		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

#### 8. **DC Characteristics**

Symbol	Parameter	Condition	100 × c0	Min	Max	Units
I <sub>LI</sub>	Input Load Current	$V_{IN} = 0V$ to $V_{CC} + 1V$	1.100Y.C	M.TW	10	μA
I <sub>LO</sub>	Output Leakage Current	$V_{I/O} = 0V$ to $V_{CC}$	100Y.C	WT.W	10	μΑ
1	V Chandley Current CMOC		Ind.	WTI	200	μA
I <sub>SB1</sub>	V <sub>CC</sub> Standby Current CMOS	$\overline{CE} = V_{CC} - 0.3V$ to $V_{CC} + 1V$	Mil.	CONTUN	300	μA
I <sub>SB2</sub>	V <sub>CC</sub> Standby Current TTL	$\overline{CE} = 2.0V$ to $V_{CC} + 1V$		CONF	3	mA
I <sub>CC</sub>	V <sub>CC</sub> Active Current	f = 5 MHz; I <sub>OUT</sub> = 0 mA	W.100	COM	50	mA
V <sub>IL</sub>	Input Low Voltage	OY.COM.TW	N 10	T.MOD	0.8	V
V <sub>IH</sub>	Input High Voltage	ODY.CO.ITH	WW	2.0	1 M	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 2.1 mA	MMM.	NOY.COM	0.45	v
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -400 μA	WW.	2.4	N/m	V



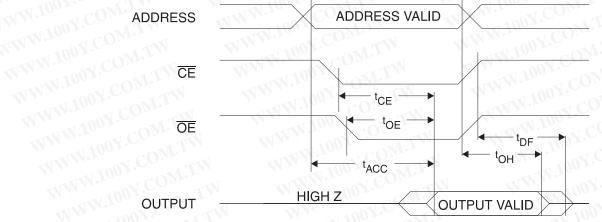
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#### **AC Read Characteristics** 9.

	WWW 100X.CC	AT28C	256-15	AT28C	256-20	AT28C	256-25	AT28C	256-35	
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Units
t <sub>ACC</sub>	Address to Output Delay	M.TV	150	An	200		250		350	ns
t <sub>CE</sub> <sup>(1)</sup>	CE to Output Delay	LING	150	MN	200	N.C.	250		350	ns
t <sub>OE</sub> <sup>(2)</sup>	OE to Output Delay	0	70	0	80	0 0	100	0	100	ns
t <sub>DF</sub> <sup>(3)(4)</sup>	CE or OE to Output Float	0	50	0 🔨	55	00.0	60	0	70	ns
t <sub>он</sub>	Output Hold from $\overline{OE}$ , $\overline{CE}$ or Address, whichever occurred first	0	N.T.W	0	M.M.M.	0	COM.	0		ns

# 10. AC Read Waveforms<sup>(1)(2)(3)(4)</sup>



- 1. CE may be delayed up to t<sub>ACC</sub> t<sub>CE</sub> after the address transition without impact on t<sub>ACC</sub>. Notes:
  - 2.  $\overline{OE}$  may be delayed up to  $t_{CE} t_{OE}$  after the falling edge of  $\overline{CE}$  without impact on  $t_{CE}$  or by  $t_{ACC} t_{OE}$  after an address change WW.100Y.COM without impact on t<sub>ACC</sub>.
  - 3.  $t_{DF}$  is specified from  $\overline{OE}$  or  $\overline{CE}$  whichever occurs first (C<sub>L</sub> = 5 pF).
  - WWW.100Y.COM.TW 4. This parameter is characterized and is not 100% tested.

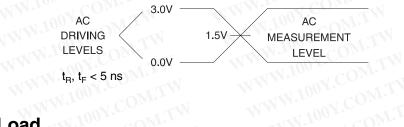


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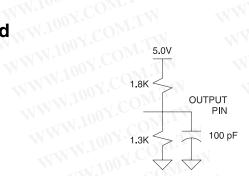
WWW.100Y.COM.TW WWW.100Y.COM.TW WWW.100Y.COM. 勝特力材料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www. 100y. com. tw

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### 11. Input Test Waveforms and Measurement Level



# WW.100Y.COM.TW 12. Output Test Load WWW.100Y.COM



# WW.100X.COM.TW 13. Pin Capacitance

f = 1 MHz, T = 25°C <sup>(1</sup>	)
-----------------------------------	---

Symbol	Тур	Max	Units	Conditions
C <sub>IN</sub>	CO4	6	pF	V <sub>IN</sub> = 0V
C <sub>OUT</sub>	8	12	pF	V <sub>OUT</sub> = 0V



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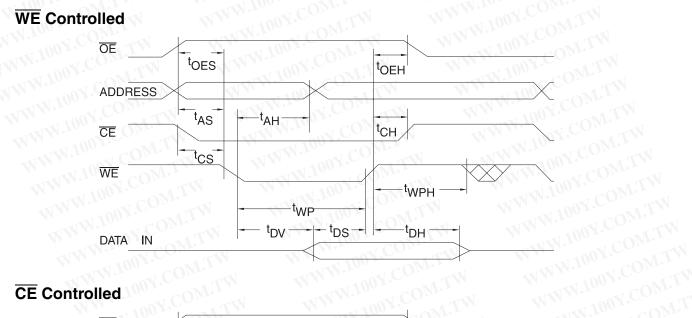


# 100Y.COM.TW 14. AC Write Characteristics

Symbol	Parameter	Min	Мах	Units
t <sub>AS</sub> , t <sub>OES</sub>	Address, OE Setup Time	0 0		ns
t <sub>AH</sub>	Address Hold Time	50	T.M.	ns
t <sub>cs</sub>	Chip Select Setup Time	WW 100Y0	WT.N	ns
t <sub>CH</sub>	Chip Select Hold Time	1000.00	WT.IM	ns
t <sub>WP</sub>	Write Pulse Width (WE or CE)	100	WT.M	ns
t <sub>DS</sub>	Data Setup Time	50	WLIN	ns
t <sub>DH</sub> , t <sub>OEH</sub>	Data, OE Hold Time	0,007.0	WILM	ns
t <sub>DV</sub>	Time to Data Valid	NR <sup>(1)</sup>	WT.	

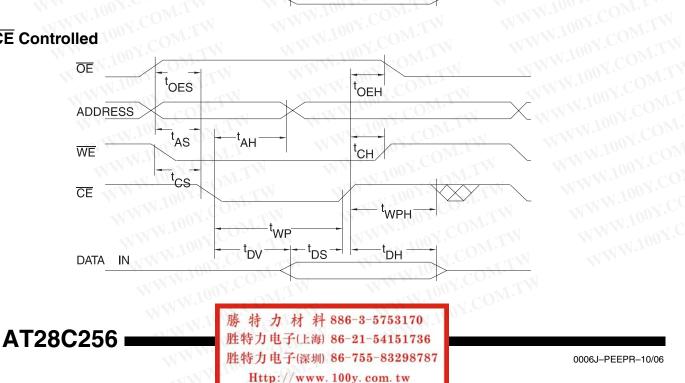
### 15. AC Write Waveforms

#### WE Controlled 15.1



# 15.2 CE Controlled

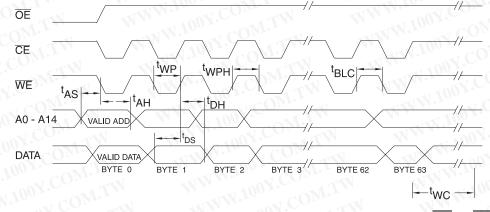
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# 16. Page Mode Characteristics

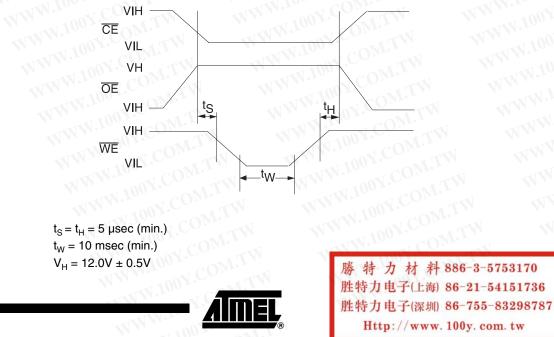
Symbol	Parameter	N NN	Min	Max	Units
COM I	Write Cycle Time (ontion sysilable)	AT28C256	N.100Y.COM.T	10	ms
twc	Write Cycle Time (option available)	AT28C256F	IN 100Y.COM	3	ms
t <sub>AS</sub>	Address Setup Time	WW WILL	100 0	TW	ns
t <sub>AH</sub>	Address Hold Time	W WILL	50	M.T.W	ns
t <sub>DS</sub>	Data Setup Time	WILL	50	WIIM	ns
t <sub>DH</sub>	Data Hold Time	WIN	007.0	WILL	ns
t <sub>WP</sub>	Write Pulse Width	COMPANY	100	WILL	ns
t <sub>BLC</sub>	Byte Load Cycle Time		NMM. 100Y	150	μs
t <sub>wPH</sub>	Write Pulse Width High	V.CONI.	50	V.COMETW	ns

# 17. Page Mode Write Waveforms<sup>(1)(2)</sup>



1. A6 through A14 must specify the same page address during each high to low transition of WE (or CE). Notes: 100Y.COM.TW 2.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.

### 18. Chip Erase Waveforms



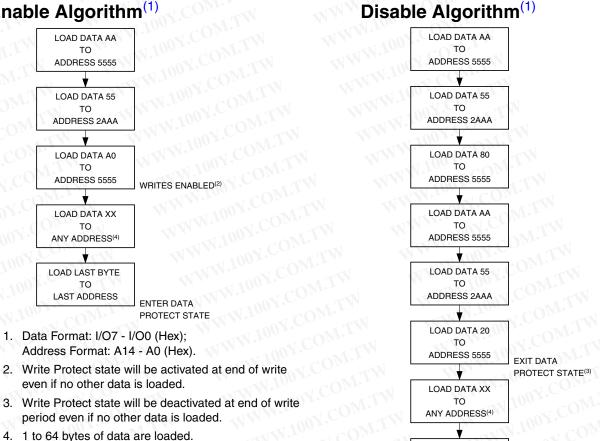


20. Software Data Protection

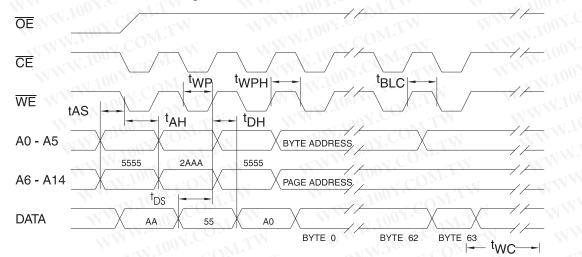
LOAD LAST BYTE TO LAST ADDRESS

### 19. Software Data Protection Enable Algorithm<sup>(1)</sup>

Notes:



## 21. Software Protected Write Cycle Waveforms<sup>(1)(2)</sup>



Notes: 1. A6 through A14 must specify the same page address during each high to low transition of WE (or CE) after the software code has been entered.

- 2.  $\overline{OE}$  must be high only when  $\overline{WE}$  and  $\overline{CE}$  are both low.
- 10 **AT28C256**

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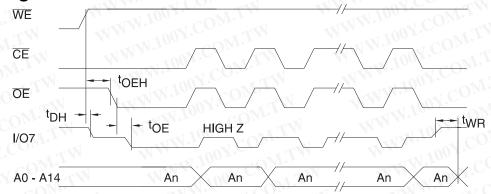
# 22. Data Polling Characteristics<sup>(1)</sup>

Symbol	Parameter	WW.10	Min	Тур	Max	Units
t <sub>DH</sub>	Data Hold Time	WWW	0 0	I.TW		ns
t <sub>OEH</sub>	OE Hold Time	WW.	000	WT.W		ns
t <sub>OE</sub>	OE to Output Delay <sup>(2)</sup>	MMI	1001.00	M.TW		ns
t <sub>WR</sub>	Write Recovery Time	MW.	0	MITH		ns

Notes: 1. These parameters are characterized and not 100% tested.

2. See"AC Read Characteristics" on page 6.

### 23. Data Polling Waveforms



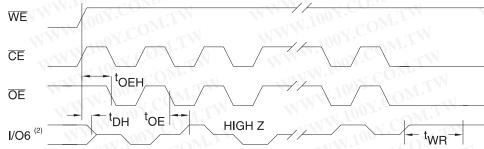
# 24. Toggle Bit Characteristics<sup>(1)</sup>

Symbol	Parameter	Min	Тур	Max	Units
t <sub>DH</sub>	Data Hold Time	10	MM.	100Y.CO.	ns
t <sub>OEH</sub>	OE Hold Time	10	WWW	100Y.CO	ns
t <sub>OE</sub>	OE to Output Delay <sup>(2)</sup>	WT	WW	100Y.C	ns
t <sub>OEHP</sub>	OE High Pulse	150	WW	N.100Y.	ns
t <sub>WR</sub>	Write Recovery Time	0	W	You.	ns

1. These parameters are characterized and not 100% tested. Notes:

2. See "AC Read Characteristics" on page 6.

# 25. Toggle Bit Waveforms<sup>(1)(2)(3)</sup>



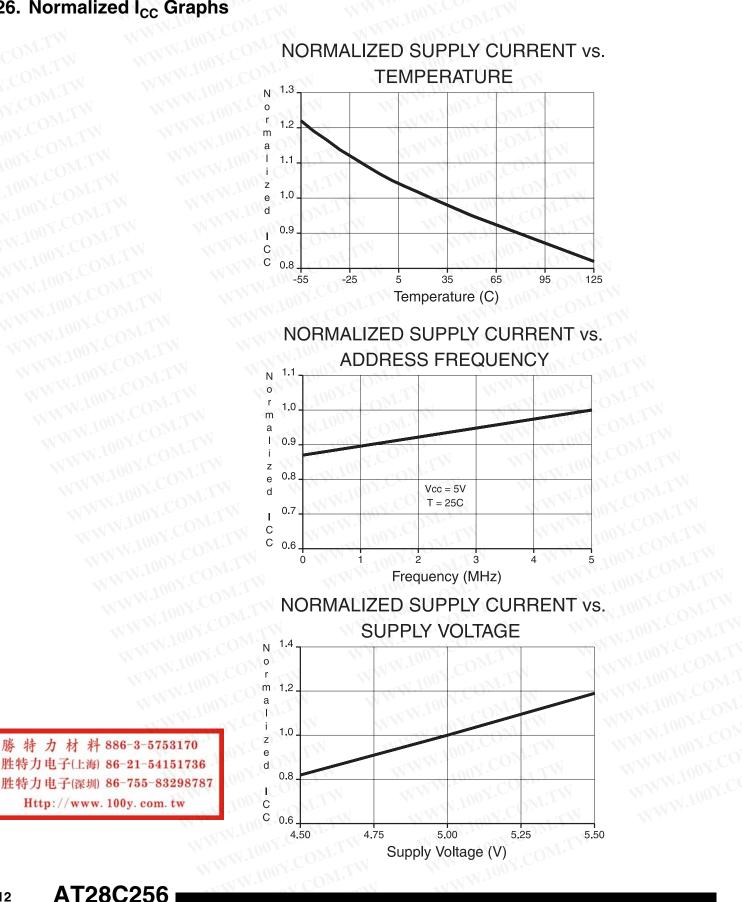
Notes: 1. Toggling either  $\overline{OE}$  or  $\overline{CE}$  or both  $\overline{OE}$  and  $\overline{CE}$  will operate toggle bit.

- 2. Beginning and ending state of I/O6 will vary.
- 3. Any address location may be used but the address should not vary.





## 26. Normalized I<sub>cc</sub> Graphs



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# 27. Ordering Information<sup>(2)</sup> W.COM.TW

#### **Standard Package** 27.1

t <sub>ACC</sub>		(mA)	N.CO. TW WW	1007.001	
(ns)	Active	Standby	Ordering Code	Package	Operation Range
150	50	0.2	AT28C256(E,F)-15JI AT28C256(E,F)-15PI AT28C256(E,F)-15SI AT28C256(E,F)-15TI	32J 28P6 28S 28T	Industrial (-40° C to 85° C)
	M.TW OM.TW COM.TW	0.3	AT28C256(E,F)-15DM/883 AT28C256(E,F)-15FM/883 AT28C256(E,F)-15LM/883 AT28C256(E,F)-15LM/883 AT28C256(E,F)-15UM/883	28D6 28F 32L 28U	Military/883C Class B, Fully Compliant (-55° C to 125° C)
200	50 COM	0.3	AT28C256(E,F)-20DM/883 AT28C256(E,F)-20FM/883 AT28C256(E,F)-20LM/883 AT28C256(E,F)-20UM/883	28D6 28F 32L 28U	Military/883C Class B, Fully Compliant (-55° C to 125° C)
250	50	0.3	AT28C256(E,F)-25DM/883 AT28C256(E,F)-25FM/883 AT28C256(E,F)-25LM/883 AT28C256(E,F)-25UM/883 AT28C256(E,F)-35UM/883	28D6 28F 32L 28U 28U 28U	Military/883C Class B, Fully Compliant (-55° C to 125° C)

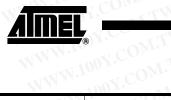
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	Http://www.100y.com.tw	WWW.100Y.COM.T
	Package Type	WW.Inv COM
28D6	28-lead, 0.600" Wide, Non-windowed, Ceramic Dual Inline Package (Cerdip)	WW.100 Y CON
28F	28-lead, Non-windowed, Ceramic Bottom-brazed Flat Package (Flatpack)	WW.100 CO
32J	32-lead, Plastic J-leaded Chip Carrier (PLCC)	W
32L	32-pad, Non-windowed, Ceramic Leadless Chip Carrier (LCC)	W W.1001.C
28P6	28-lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)	IM WW.1001.
28S	28-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)	LTW WW.100X
28T	28-lead, Plastic Thin Small Outline Package (TSOP)	M.TW WW.100
28U	28-pin, Ceramic Pin Grid Array (PGA)	MITH WWW.10
W	Die	WITH WITH
	Options	WITH WITH
Blank	Standard Device: Endurance = 10K Write Cycles; Write Time = 10 ms	COWLIN MAN.
Е	High Endurance Option: Endurance = 100K Write Cycles	LCOMTW
F	Fast Write Option: Write Time = 3 ms	<1 COM.





#### Standard Package (Continued) 27.1

t <sub>ACC</sub>	I <sub>cc</sub>	(mA)		100Y.COMIT	2
(ns)	Active	Standby	Ordering Code	Package	Operation Range
150 <sup>(3)</sup>	50	0.3	5962-88525 16 UX	28U	Military/883C
	W	WW	5962-88525 16 XX	28D6	Class B, Fully Compliant
COM.	W	WWW	5962-88525 16 YX	32L	(-55° C to 125° C)
COM		WW	5962-88525 16 ZX	28F	W
Y.C	A.T.W		5962-88525 15 UX	28U	Militory/082C
NY.CO.	WIN	MM	5962-88525 15 XX	28D6	Military/883C
20.V	W	WW	5962-88525 15 YX	32L	Class B, Fully Compliant
	OM. L		5962-88525 15 ZX	28F	(-55° C to 125° C)
1001.	· MO		5962-88525 14 UX	28U	Military/883C
1001.	TIM		5962-88525 14 XX	28D6	Class B, Fully Compliant
V.L.	COm	V V	5962-88525 14 YX	32L	(-55° C to 125° C)
W.100	. COM.,		5962-88525 14 ZX	28F	(-55 C to 125 C)

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	Package Type
BD6	28-lead, 0.600" Wide, Non-windowed, Ceramic Dual Inline Package (Cerdip)
8F	28-lead, Non-windowed, Ceramic Bottom-brazed Flat Package (Flatpack)
2J	32-lead, Plastic J-leaded Chip Carrier (PLCC)
2L	32-pad, Non-windowed, Ceramic Leadless Chip Carrier (LCC)
BP6	28-lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)
8U	28-pin, Ceramic Pin Grid Array (PGA)
w	Die WWW.001.001.001.001.001.001.001.001.001.
	Options
ank	Standard Device: Endurance = 10K Write Cycles; Write Time = 10 ms
E	High Endurance Option: Endurance = 100K Write Cycles
F	Fast Write Option: Write Time = 3 ms

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WWW.100X.CC

#### AT28C256 14

#### Standard Package (Continued) 27.1

t <sub>ACC</sub>	I <sub>cc</sub>	(mA)	V.COM WY	M. OY.COM	2
(ns)	Active	Standby	Ordering Code	Package	Operation Range
150 <sup>(3)</sup>	50	0.3	5962-88525 08 UX 5962-88525 08 XX 5962-88525 08 YX 5962-88525 08 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55° C to 125° C)
	M.TW M.TW OM.TW	N.M.	5962-88525 07 UX 5962-88525 07 XX 5962-88525 07 YX 5962-88525 07 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55°C to 125°C)
	COM.TV COM.TV COM.T		5962-88525 06 UX 5962-88525 06 XX 5962-88525 06 YX 5962-88525 06 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55° C to 125° C)
200 <sup>(3)</sup>	50	0.3	5962-88525 12 UX 5962-88525 12 XX 5962-88525 12 YX 5962-88525 12 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55°C to 125°C)
	50	0.3	5962-88525 04 UX 5962-88525 04 XX 5962-88525 04 YX 5962-88525 04 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55°C to 125°C)
250 <sup>(3)</sup>	50	0.3	5962-88525 13 UX 5962-88525 13 XX 5962-88525 13 YX 5962-88525 13 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55°C to 125°C)
	WWW.I	00Y.CON	5962-88525 11 UX 5962-88525 11 XX 5962-88525 11 YX 5962-88525 11 ZX	28U 28D6 32L 28F	Military/883C Class B, Fully Compliant (-55° C to 125° C)

	Package Type
28D6	28-lead, 0.600" Wide, Non-windowed, Ceramic Dual Inline Package (Cerdip)
28F	28-lead, Non-windowed, Ceramic Bottom-brazed Flat Package (Flatpack)
32L	32-pad, Non-windowed, Ceramic Leadless Chip Carrier (LCC)
28U	28-pin, Ceramic Pin Grid Array (PGA)
W	Die
	Options
Blank	Standard Device: Endurance = 10K Write Cycles; Write Time = 10 ms
Е	High Endurance Option: Endurance = 100K Write Cycles
F	Fast Write Option: Write Time = 3 ms



MMW.



#### **Standard Package (Continued)** 27.1

t <sub>ACC</sub>	I <sub>CC</sub>	(mA)	V.COMP.	NT.COM TV	
(ns)	Active	Standby	Ordering Code	Package	<b>Operation Range</b>
250	50	0.3	5962-88525 05 UX	28U	Military/883C
	W	WW	5962-88525 05 XX	28D6	Class B, Fully Compliant
	- N	WWW	5962-88525 05 YX	32L	(-55° C to 125° C)
		VIII	5962-88525 05 ZX	28F	
	MT.IM		5962-88525 03 UX	28U	Military/883C
	WTI	MW.	5962-88525 03 XX	28D6	Class B, Fully Compliant
	WT	WW	5962-88525 03 YX	32L	(-55° C to 125° C)
	OM.		5962-88525 03 ZX	28F	
300	50	0.3	5962-88525 10 UX	28U	Military/883C
	TI		5962-88525 10 XX	28D6	Class B, Fully Compliant
	COM.	× N	5962-88525 10 YX	32L	(-55° C to 125° C)
	COM.	- N	5962-88525 10 ZX	28F	
	50	0.3	5962-88525 02 UX	28U	Military/883C
	OV.CON	WT.	5962-88525 02 XX	28D6	Class B, Fully Compliant
	Jon V.COM	WT	5962-88525 02 YX	32L	(-55° C to 125° C)
	LUC CO	M L	5962-88525 02 ZX	28F	
350	50	0.3	5962-88525 09 UX	28U	Military/883C
	U 100Y.C	M.T.W	5962-88525 09 XX	28D6	Class B, Fully Compliant
	Y.OOY.C	WT	5962-88525 09 YX	32L	(-55° C to 125° C)
	W.IV.	COMPT	5962-88525 09 ZX	28F	
	50	0.3	5962-88525 01 UX	28U	Military/883C
	100	T.MONT	5962-88525 01 XX	28D6	Class B, Fully Compliant
	WW.	Y.COM	5962-88525 01 YX	32L	(-55° C to 125° C)
	WW.LO	COM.	5962-88525 01 ZX	28F	

Notes: 1. Electrical specifications for these speeds are defined by Standard Microcircuit Drawing 5962-88525.

2. See "Valid Part Numbers" on page 18.

3. SMD specifies Software Data Protection feature for device type, although Atmel product supplied to every device type in the WWW.100Y. SMD is 100% tested for this feature.

	Package Type
28D6	28-lead, 0.600" Wide, Non-windowed, Ceramic Dual Inline Package (Cerdip)
28F	28-lead, Non-windowed, Ceramic Bottom-brazed Flat Package (Flatpack)
32L	32-pad, Non-windowed, Ceramic Leadless Chip Carrier (LCC)
28U	28-pin, Ceramic Pin Grid Array (PGA)
W	Die COM IN COM IN COM
	Options
Blank	Standard Device: Endurance = 10K Write Cycles; Write Time = 10 ms
Е	High Endurance Option: Endurance = 100K Write Cycles
F	Fast Write Option: Write Time = 3 ms

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(ns)	Active	Standby	Ordering Code	Package	Operation Range
150	50	0.2	AT28C256(F)-15JU	32J	Industrial
	T.M.	N N	AT28C256(F)-15PU	28P6	(-40° C to 85° C)
	WT	NW .	AT28C256(F)-15SU	28S	TW.
		WWW	AT28C256(F)-15TU	28T	WT -

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	Package Type			
32J	32-lead, Plastic J-leaded Chip Carrier (PLCC)			
28P6	28-lead, 0.600" Wide, Plastic Dual Inline Package (PDIP)			
28S	28-lead, 0.300" Wide, Plastic Gull Wing Small Outline (SOIC)			
28T	28-lead, Plastic Thin Small Outline Package (TSOP)			
	Options			
Blank	Standard Device: Endurance = 10K Write Cycles; Write Time = 10 ms			
F	Fast Write Option: Write Time = 3 ms			





# DOX.COM.TW 28. Valid Part Numbers

Device Numbers	Speed	Package and Temperature Combinations
AT28C256	15	JI, JU, PI, PU, SI, SU, TI, TU, DM/883, FM/883, LM/883, UM/883
AT28C256E	15	JI, PI, SI, TI, DM/883, FM/883, LM/883, UM/883
AT28C256F	15	JI, JU, PI, PU, SI, SU, TI, TU, DM/883, FM/883, LM/883, UM/883
AT28C256	20	DM/883, FM/883, LM/883, UM/883
AT28C256E	20	DM/883, FM/883, LM/883, UM/883
AT28C256F	20	DM/883, FM/883, LM/883, UM/883
AT28C256	25	DM/883, FM/883, LM/883, UM/883
AT28C256E	25	DM/883, FM/883, LM/883, UM/883
AT28C256F	25	DM/883, FM/883, LM/883, UM/883

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### 29. Die Products

Reference Section: Parallel EEPROM Die Products WWW.100X WWW.100Y.COM.T

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WWW.100Y.COM.

WWW.10

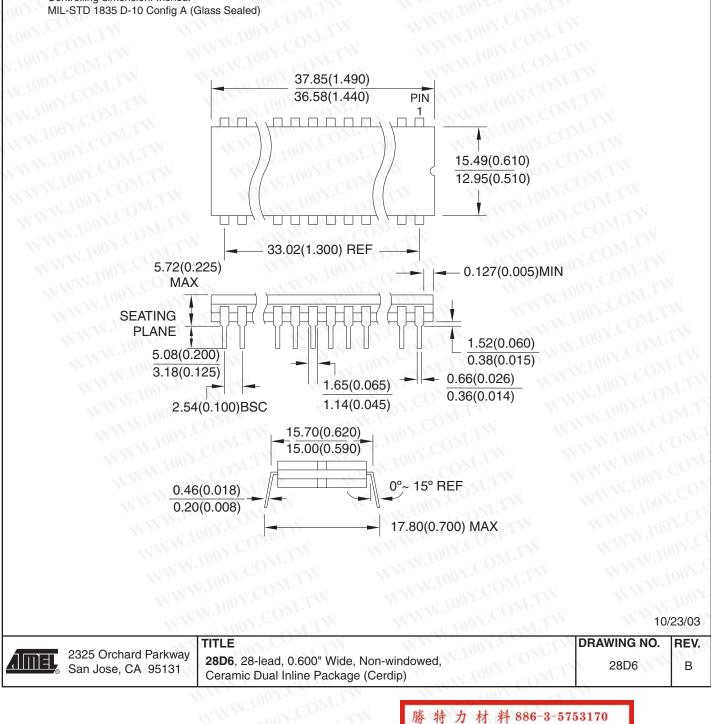
N.COM.TW

MT.MO

## **Packaging Information**

### 29.1 28D6 - Cerdip

Dimensions in Millimeters and (Inches). Controlling dimension: Inches. MIL-STD 1835 D-10 Config A (Glass Sealed)



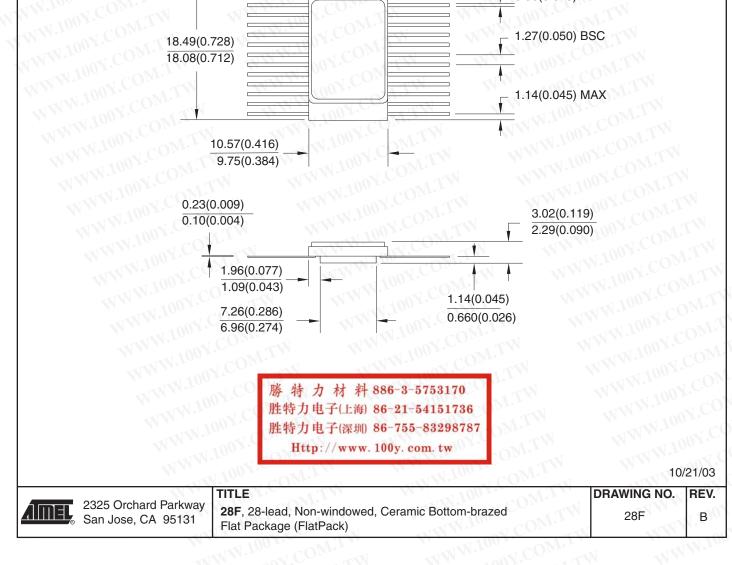
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#### 28F – Flatpack 29.2

Dimensions in Millimeters and (Inches). Controlling dimension: Inches. WWW.100Y.COM MIL-STD 1835 F-12 Config B WWW.100Y.COM.TW

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PIN #1 ID --

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C Б

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9.40(0.370)

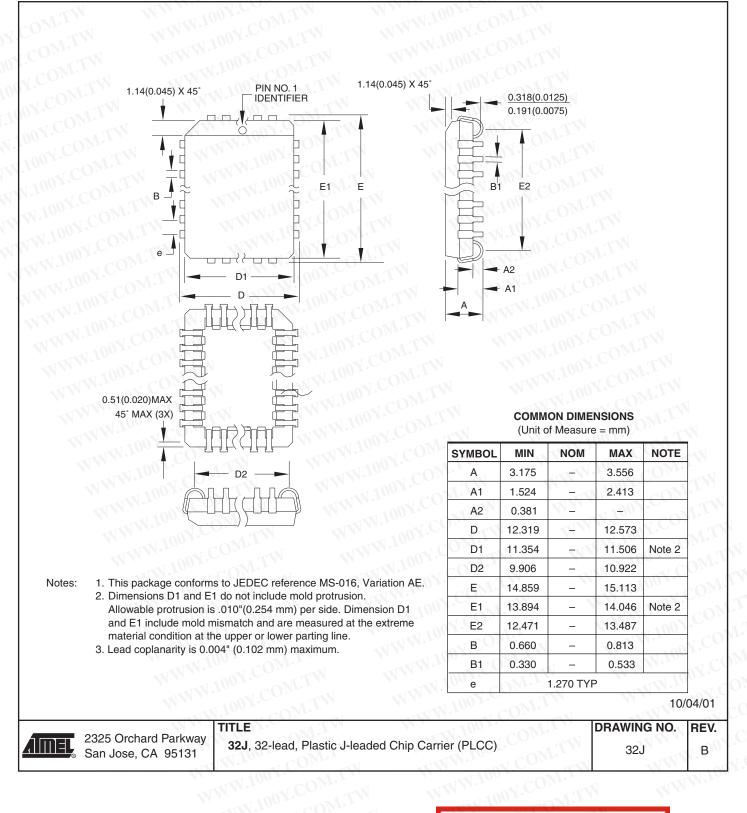
6.35(0.250)

0.56(0.022)

0.38(0.015)

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29.3 32J - PLCC

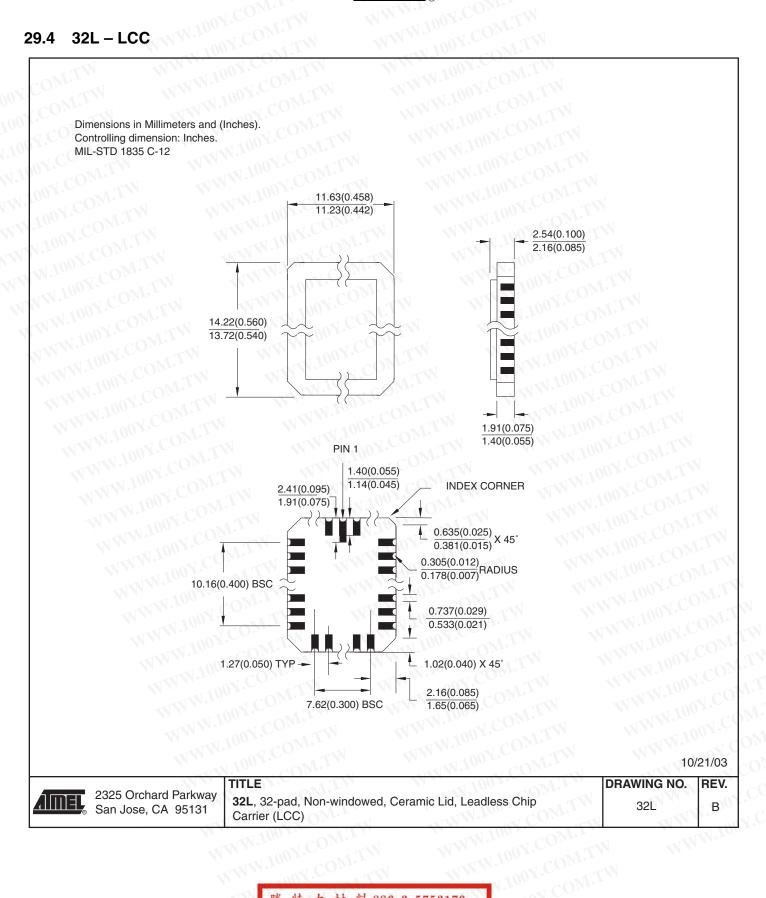


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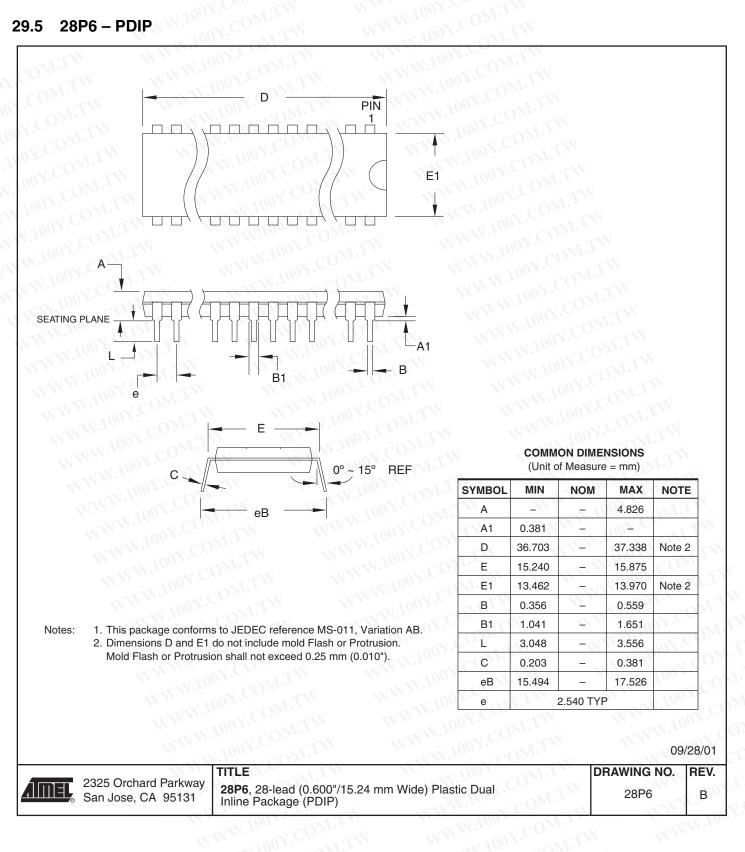
#### 32L – LCC 29.4



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WWW.1007

WWW.100Y.COM.

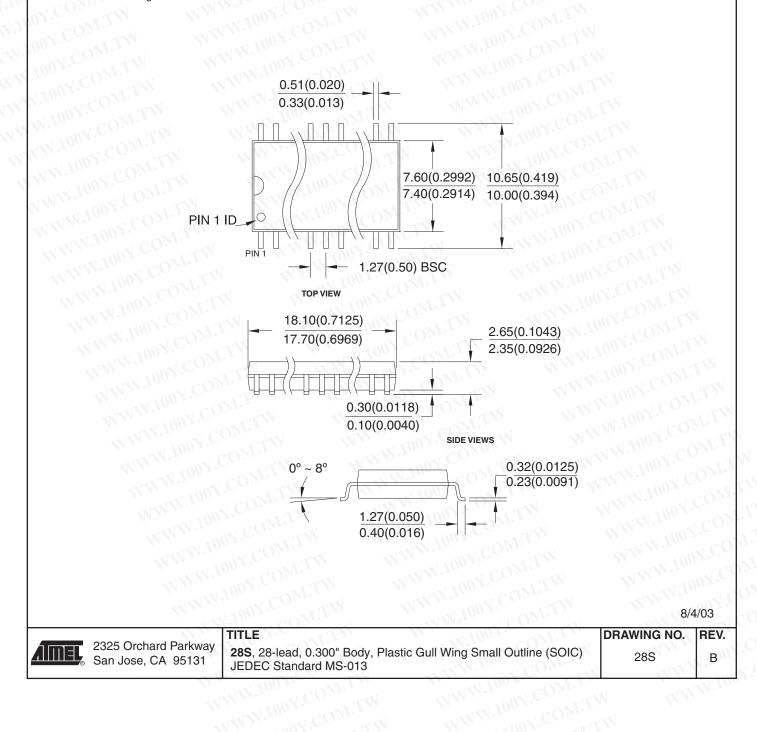
#### 28S – SOIC 29.6

Dimensions in Millimeters and (Inches). Controlling dimension: Millimeters.

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W.100Y.COM.T

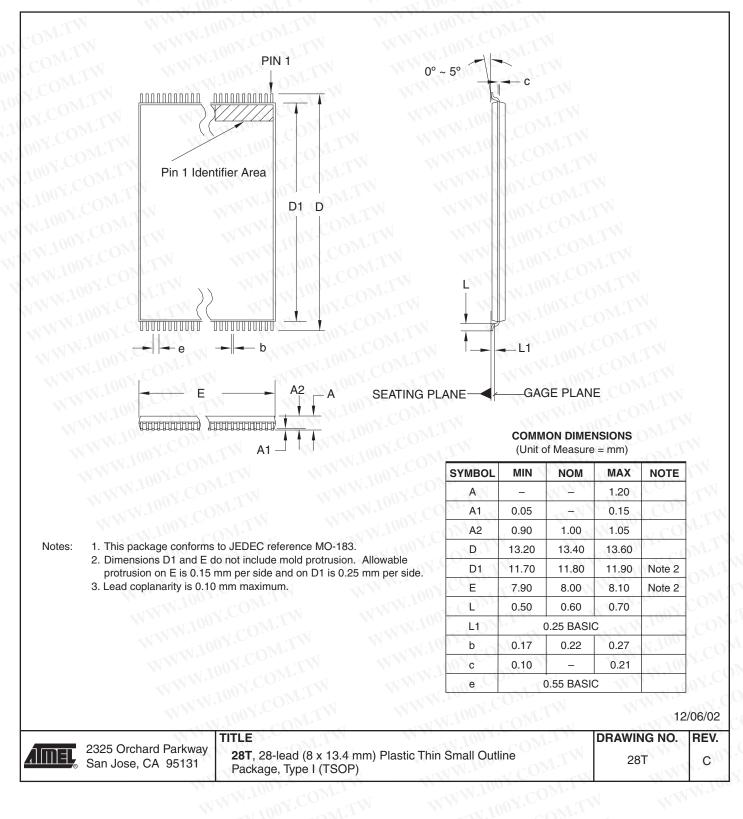


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29.7 28T - TSOP





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WWW.100X

WWW.100Y.COM.

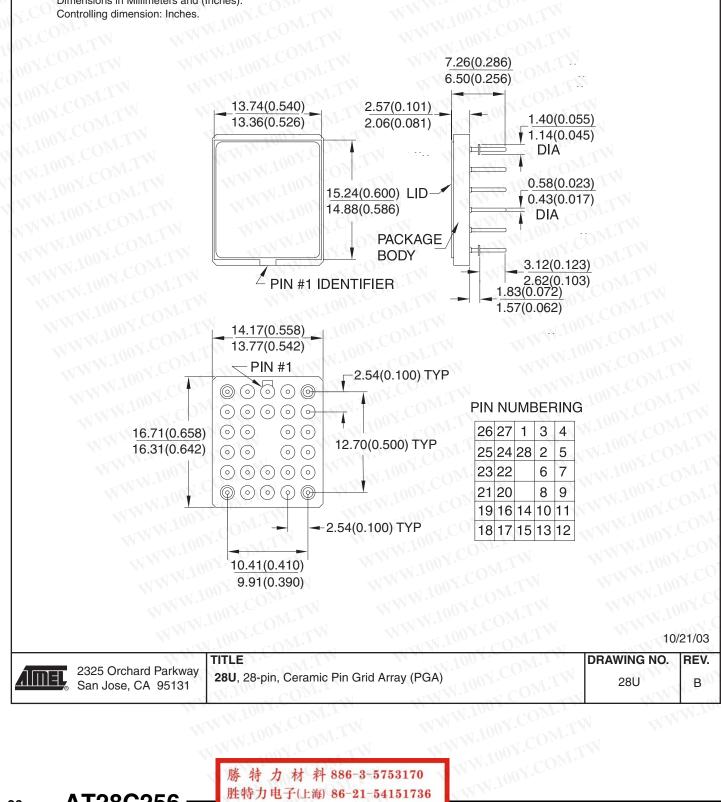
# 28U – PGA 29.8

Dimensions in Millimeters and (Inches). Controlling dimension: Inches.

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AT28C256



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